## **Supplementary Information**

## Permanent photodoping of plasmonic gallium-ZnO nanocrystals

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Fig. S1. Transmission electron microscopy images of ZnO and Ga doped samples



Fig. S2. Overview spectra for undoped and Ga doped ZnO samples.



Fig. S3. Zn 2p spectra for undoped and Ga doped ZnO samples.



Fig. S4. O 1s spectrum of GZO 30 before and after UV irradiation in n-butanol



**Fig. S5.** UV-vis-NIR absorption spectra of various powder samples before and after 72 h photodoping. and relaxation after storing in air for 2 and 4 weeks.

Sample nominal Ga% (%)	Band gap	
0	3.21	
2.5	3.19	
5	3.13	
7.5	3.18	
10	3.16	
15	3.16	
20	3.13	
25	3.13	
30	3.13	

40 ZnO -GZO2.5 GZO5 40 40  $\begin{array}{c} 30\\ (ahv)^2\\ \end{array}$  $(ahn)^{2}$  $(ahv)^{2}$ 10 10 (b) 10 (a) (c)  $0 \downarrow 2.9$ 0 0 3.1 3.2 3.3 Energy (eV) 3.4 <sup>3.0</sup> <sup>3.1</sup> <sup>3.2</sup> <sup>3.3</sup> <sup>3.4</sup> Energy (eV) 3.0 3.5 3.5 3.6 <sup>3.0</sup> <sup>3.1</sup> <sup>3.2</sup> <sup>3.3</sup> <sup>3.4</sup> Energy (eV) 3.5 3.6 2.8 2.9 2.8 2.9 GZO7.5 GZO10 - GZO15 40 40 40  $(ahv)^{2}_{00}$  $(ahv)^{2}_{30}$  $(ahn)^{20}$ 10 -10 10 (d) (e) (f) 0 0 <sup>3.0</sup> <sup>3.1</sup> <sup>3.2</sup> <sup>3.3</sup> <sup>3.4</sup> Energy (eV) 3.5 3.6 <sup>3.0</sup> <sup>3.1</sup> <sup>3.2</sup> <sup>3.3</sup> <sup>3.4</sup> Energy (eV) 3.5 3.6 3.6 <sup>3.0</sup> <sup>3.1</sup> <sup>3.2</sup> <sup>3.3</sup> <sup>3.4</sup> Energy (eV) 2.8 3.5 2.9 2.8 2.9 2.8 2.9 GZO30 GZO20 -GZO25 40 40 -30  $(ahv)^{20}$ 30  $(ahv)^2$  $(ahv)^2$ 10 10 10 (h) (g) (i) 0 2.8 2.9 0 0 <sup>3.0</sup> <sup>3.1</sup> <sup>3.2</sup> <sup>3.3</sup> <sup>3.4</sup> Energy (eV) 3.5 3.6 <sup>3.0</sup> <sup>3.1</sup> <sup>3.2</sup> <sup>3.3</sup> <sup>3.4</sup> Energy (eV) 3.5 3.6 <sup>3.0</sup> <sup>3.1</sup> <sup>3.2</sup> <sup>3.3</sup> Energy (eV) 3.5 3.6 2.8 2.9 2.9 3.4

Fig. S6.  $(\alpha hv)^2$  versus energy for ZnO and Ga doped samples.

Table S1. The band gap values for ZnO and GZO samples



Fig. S7. XRD for GZO 30 and GZO 30 UV samples.



**Fig. S8.** TEM images for GZO 30 samples before (GZO 30) and after UV (GZO 30 +UV) irradiation.

	23 Na	66 Zn	71 Ga	23 Na	66 Zn	71 Ga
	mg/L			% from synthesis solution		
Synthesis solution	4901	9.32	103	100	100	100
n-butanol supernatant	4.94	0.223	0.018	0.10	2.39	0.02

 Table S2. ICP-MS measurements for supernatants after synthesis and before UV irradiation



Fig. S9. UV-vis-NIR absorption spectra of indium doped tin oxide (ITO) nanopowder (particle size 30 nm) from Sigma-Aldrich before, after and 4 weeks after UVC photodoping.